#### LITE-ON TE SEMICONDUCTOR

# **SD1A150A**

MAX.

4.57

2.92

1.63

0.31

5.59

0.20

2.40

1.52

#### SIDAC HIGH VOLTAGE **1 AMPERE** SILLICON UNIDRECTIONAL THYSISTORS **150 VOLTS FEATURES** <u>SM</u>A $\bullet$ V\_{BO} range is from 142 to 157 Vdc • V<sub>DRM</sub> with stand 120V SMA • $I_H$ is under 60 mA DIM. MIN. • Compact package for spacing saving. 4.06 A в 2.29 С 1.27 Application D 0.15 • Gas Igniters Е 4.83 F 0.05 G 1.96 **MECHANICAL DATA** н 0.76 Case: JEDEC DO-214AC molded plastic All Dimensions in millimeter • Terminals: Lead Free Plating Marking Component in accordance to RoHs 2011/65/EU • UL Recognition File # E219635 LT YMWW SD1A15

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

### ABSOLUTE RATING

PARMETER	TEST CONDITION	SYMBOL	VALUE			UNIT
Peak repetitive off-state voltage	TJ= -40 to 125°C, sine wave, 50 to 60 Hz	V <sub>DRM</sub>	120			V
On-state RMS current	$TL = 80^{\circ}C$ , all conduction angles	I <sub>T(RMS)</sub>	1			A
		IT(RMS)	280			
Pulse on-state current	Ta=25°C, pulse width to = 10us, $f=5Hz$ sine wave, repetitive peak value $f=60Hz$	I <sub>TRM</sub>		120	Α	
Maximum lead solder temperature (	Lead length $\geq$ 1/16 " from case, 10s max)	TL	260			°C
Operating junction temperature range		TJ	-40 ~ +125			°C
Storage temperature range		T <sub>STG</sub>	-40 ~ +150			°C
THERMAL PERFORMANCE						
F	PARMETER	SYMBOL	TYP.			UNIT
Typical thermal resistance junction to case		RthJ <sub>c</sub>	15			°C/W
OFF CHARACTERISTICS		•				
F	PARMETER	SYMBOL	MAX			UNIT
Peak repetitive forward or reverse blocking current (50 to 60 Hz) $V_{\text{DRM}}$ =120V		I <sub>DRM</sub>	10			uA
ON CHARACTERISTICS		•				
PARMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Peak on-state voltage	I <sub>T</sub> = 1 A	V <sub>TM</sub>		1.1	1.5	V
Break over voltage	I <sub>BO</sub> = 5 uA	V <sub>BO</sub>	142	150	157	V
Break over current		I <sub>BO</sub>			200	uA
Holding current		I <sub>H</sub>			60	mA
Switching resistance		Rs	0.1			kΩ
ON CHARACTERISTICS						·
PARMETER		SYMBOL	MIN	TYP.	MAX	UNIT

PARMETER		MIN	TYP.	MAX	UNIT
Critical rate of rise of on-state current			80		A/uS
Note :		REV-2, JUN2017, KSXA03			3

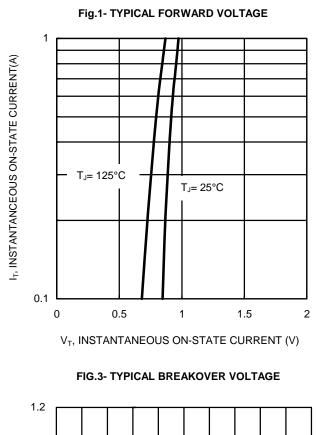
Maximum ratings are those values beyond which device damage can occur.

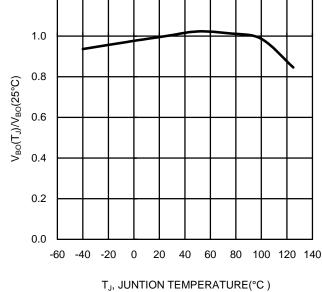
Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously.

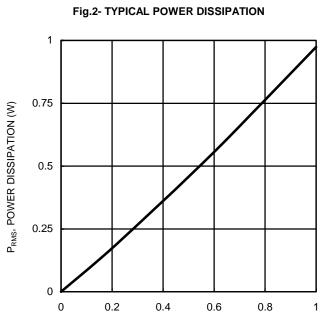
If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



# RATING AND CHARACTERISTIC CURVES SD1A150A

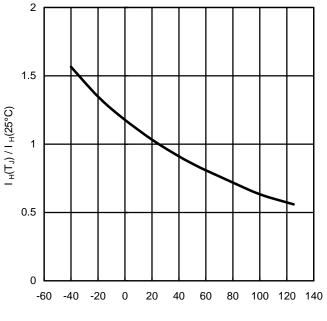






 $I_{T(RMS)},$  ON-STATE CURRENT (A)

#### Fig.4- TYPICAL HOLDING CURRENT



 $T_{\text{J}},$  JUNTION TEMPERATURE(°C )



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